



RC4200 Analog Multiplier

Features

- High accuracy
- Nonlinearity 0.1%
- Temperature coefficient 0.005%/°C
- Multiple functions
- Multiply, divide, square, square root, RMS-to-DC conversion, AGC and modulate/demodulate
- Wide bandwidth 4 MHz
- Signal-to-noise ratio 94 dB

Applications

- · Low distortion audio modulation circuits
- Voltage-controlled active filters
- Precision oscillators

Description

The RC4200 analog multiplier has complete compensation for nonlinearity, the primary source of error and distortion. This multiplier also has three onboard operational amplifiers designed specifically for use in multiplier logging circuits. These amplifiers are frequency compensated for optimum AC response in a logging circuit, the heart of a multiplier, and can therefore provide superior AC response.

The RC4200 can be used in a wide variety of applications without sacrificing accuracy. Four-quadrant multiplication, two-quadrant division, square rooting, squaring and RMS conversion can all be easily implemented with predictable accuracy. The nonlinearity compensation is not just trimmed at a single temperature, it is designed to provide compensation over the full temperature range. This nonlinearity compensation combined with the low gain and offset drift inherent in a well-designed monolithic chip provides a very high accuracy and a low temperature coefficient.

Block Diagram



Functional Description

The RC4200 multiplier is designed to multiply two input currents (I₁ and I₂) and to divide by a third input current (I4). The output is also in the form of a current (I3). A simplified circuit diagram is shown in the Block Diagram. The nominal relationship between the three inputs and the output is:

$$I_3 = \frac{I_1 I_2}{I_4}$$
 (1)

The three input currents must be positive and restricted to a range of 1 μ A to 1 mA. These currents go into the multiplier chip at op amp summing junctions which are nominally at zero volts. Therefore, an input voltage can be easily converted to an input current by a series resistor. Any number of currents may be summed at the inputs. Depending on the application, the output current can be converted to a voltage by an external op amp or used directly. This capability of combining input currents and voltages in various combinations provides great versatility in application.

Inside the multiplier chip, the three op amps make the collector currents of transistors Q1, Q2 and Q4 equal to their respective input currents (I₁, I₂, and I₄). These op amps are designed with current source outputs and are phase-compensated for optimum frequency response as a multiplier. Power drain of the op amps was minimized to prevent the introduction of undesired thermal gradients on the chip. The three op amps operate on a single supply voltage (nominally -15V) and total quiescent current drain is less than 4 mA. These special op amps provide significantly improved performance in comparison to 741-type op amps.

The actual multiplication is done within the log-antilog configuration of the Q1-Q4 transistor array. These four transistors, with associated proprietary circuitry, were specially designed to precisely implement the relationship.

$$V_{BEN} = \frac{kT}{Q} In \frac{I_{CN}}{I_{SN}} \quad (2)$$

Previous multiplier designs have suffered from an additional undesired linear term in the above equation; the collector current times the emitter resistance. The I_{CTE} term introduces a parabolic nonlinearity even with matched transistors. Fairchild Semiconductor has developed a unique and proprietary means of inherently compensating for this undesired I_{CTE} term. Furthermore, this Fairchild Semiconductor developed circuit technique compensates linearity error over temperature changes. The nonlinearity versus temperature is significantly improved over earlier designs.

From equation (2) and by assuming equal transistor junction temperatures, summing base-to-emitter voltage drops around the transistor array yields:

$$\frac{\mathrm{KT}}{\mathrm{q}} \left[\mathrm{In} \frac{\mathrm{I}_{1}}{\mathrm{I}_{\mathrm{S1}}} = \mathrm{In} \frac{\mathrm{I}_{2}}{\mathrm{I}_{\mathrm{S2}}} - \mathrm{In} \frac{\mathrm{I}_{3}}{\mathrm{I}_{\mathrm{S3}}} - \mathrm{In} \frac{\mathrm{I}_{4}}{\mathrm{I}_{\mathrm{S4}}} \right] = 0 \quad (3)$$

This equation reduces to:

$$\frac{I_1 I_2}{I_3 I_4} = \frac{I_{S1} I_{S2}}{I_{S3} I_{S4}} \quad (4)$$

The rate of reverse saturation current IS1IS2/IS3IS4, depends on the transistor matching. In a monolithic multiplier this matching is easily achieved and the rate is very close to unity, typically $1.0\pm1\%$. The final result is the desired relationship:

$$I_3 = \frac{I_1 I_2}{I_4}$$
 (5)

The inherent linearity and gain stability combined with low cost and versatility makes this new circuit ideal for a wide range of nonlinear functions.

Pin Assignments



Absolute Maximum Ratings

Parameter	Min.	Max.	Unit	
Supply Voltage ¹			-22	V
Input Current			-5	mA
Storage Temperature Range	RM4200/4200A	-65	+150	°C
	RC4200/4200A	-55	+125	°C
Operating Temperature Range	RM4200/4200A	-55	+125	°C
	RC4200/4200A	0	+70	°C

Notes:

1. For a supply voltage greater than -22V, the absolute maximum input voltage is equal to the supply voltage.

2. Observe package thermal characteristics.

Thermal Characteristics

(Still air, soldered into PC board)

	8-Lead Plastic DIP	8-Lead SOIC	8-Lead Ceramic DIP
Maximum Junction Temperature	+125°C	+125°C	+175°C
Maximum PD TA < 50°C	468mW	300mW	833mW
Thermal Resistance θJC	—	—	45°C/W
Thermal Resistance θJA	160°C/W	240°C/W	150°C/W
For $T_A > 50^{\circ}C$ Derate at	6.25mW/°C	4.17mW/°C	8.33mW/°C

Electrical Characteristics

(Over operating temperature range, Vs = -15V unless otherwise noted)

		4200A		4200				
Parameters	Test Conditions	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Total Error as Multiplier	TA = +25°C							
	Untrimmed ¹			±2.0			±3.0	%
	With External Trim		±0.2			±0.2		%
	Versus Temperature		±0.005			±0.005		%/°C
	Versus Supply (-9 to -18V)		±0.1			±0.1		%/V
Nonlinearity ²	50μA ≤ I1,2,4 ≤ 250 μA, T _A = +25°C			±0.1			±0.3	%
Input Current Range (I ₁ , I ₂ and I ₄)		1.0		1000	1.0		1000	μΑ
Input Offset Voltage	I ₁ = I ₂ = I ₄ = 150 μA T _A = +25°C			±5.0			±10	mV
Input Bias Current	I ₁ = I ₂ = I ₄ = 150 μA T _A = +25°C			300			500	nA
Average Input Offset Voltage Drift	l1 = l2 = l4 = 150 μA			±50			±100	μV/°C
Output Current Range (I ₃) ³		1.0		1000	1.0		1000	μΑ

Electrical Characteristics (continued)

(Over operating temperature range, Vs = -15V unless otherwise noted)

			4200A		4200			
Parameters	Test Conditions	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Response, -3dB point Supply Voltage		-18	4.0 -15	-9.0	-18	4.0 -15	-9.0	MHz V
Supply Current	$I_1 = I_2 = I_4 = 150 \ \mu A$ TA = +25°C			4.0			4.0	mA

Notes:

1. Refer to Figure 6 for example.

2. The input circuits tend to become unstable at I₁, I₂, I₄ < 50 μ A and linearity decreases when I₁, I₂, I₄ > 250 μ A (eq. @ I₁ = I₂ = 500 μ A, nonlinearity error \approx 0.5%).

3. These specifications apply with output (I₃) connected to an op amp summing junction. If desired, the output (I₃) at pin (4) can be used to drive a resistive load directly. The resistive load should be less than 700Ω and must be pulled up to a positive supply such that the voltage on pin (4) stays within a range of 0 to +5V.

Applications Discussion

Current Multiplier/ Divider

The basic design criteria for all circuit configurations using the RC4200 multiplier is contained in equation (1), that is,

$$\mathbf{I}_3 = \frac{\mathbf{I}_1 \mathbf{I}_2}{\mathbf{I}_4}$$

The current-product-balance equation restates this as:

$$I_1 I_2 = I_3 I_4$$
 (6)



Figure 1. Current Multiplier/Divider

Dynamic Range and Stability

The precision dynamic range for the RC4200 is from $+50 \ \mu A$ to $+250 \ \mu A$ inputs for I₁, I₂ and I₄. Stability and accuracy degrade if this range is exceeded.

To improve the stability for input currents less than 50 μ A, filter circuits (RSCS) are added to each input (see Figure 2).



Figure 2. Current Multiplier/Divider with Filters

Amplifier A1 is used to convert the I3 current to an output voltage.

Multiplier: $Vz = constant \neq 0$ Divider: $Vy = constant \neq 0$

Voltage Multiplier/Divider



Figure 3. Voltage Multiplier/Divider

Solving for $V_0 = \frac{V_X V_Y - R_0 R_4}{V_Z - R_1 R_2}$

For a multiplier circuit $V_Z = V_R = constant$

Therefore:
$$V_0 = V_X V_Y K$$
 where $K = \frac{R_0 R_4}{V_R R_1 R_2}$

For a divider circuit $V_{Y} = V_{R} = constant$

Therefore:
$$V_0 = \frac{V_X}{V_Z} K$$
 where $K = \frac{V_R R_0 R_4}{R_1 R_2}$

Extended Range

The input and output voltage ranges can be extended to include 0 and negative voltage signals by adding bias currents. The RSCS filter circuits are eliminated when the input and biasing resistors are selected to limit the respective currents to 50 µA min. and 250 µA max.

Extended Range Multiplier



Figure 4. Extended Range Multiplier

Resistors Ra and Rb extend the range of the VX and VY inputs by picking values such that:

$$I_{1}(\min.) = \frac{V_{X}(\min.)}{R_{1}} + \frac{V_{REF}}{R_{a}} = 50 \ \mu\text{A},$$

and $I_{1}(\max.) = \frac{V_{X}(\max.)}{R_{1}} + \frac{V_{REF}}{R_{a}} = 250 \ \mu\text{A},$
also $I_{2}(\min.) = \frac{V_{Y}(\min.)}{R_{2}} + \frac{V_{REF}}{R_{b}} = 50 \ \mu\text{A},$
and $I_{2}(\max.) = \frac{V_{Y}(\max.)}{R_{2}} + \frac{V_{REF}}{R_{b}} = 250 \ \mu\text{A}.$

Resistor RC supplies bias current for I3 which allows the output to go negative.

Resistors RCX and RCY permit equation (6) to balance, ie.:

$$\begin{pmatrix} \frac{V_X}{R_1} + \frac{V_{REF}}{R_a} \end{pmatrix} \begin{pmatrix} \frac{V_Y}{R_2} + \frac{V_{REF}}{R_b} \end{pmatrix} = \begin{pmatrix} \frac{V_0}{R_0} + \frac{V_{REF}}{R_C} + \frac{V_X}{R_{CX}} + \frac{V_Y}{R_{CY}} \end{pmatrix}$$

$$\frac{V_Y V_X}{R_1 R_2} + \frac{V_X V_{REF}}{R_1 R_b} + \frac{V_Y V_{REF}}{R_2 R_a} + \frac{V_{REF}}{R_a R_b} =$$

$$\frac{V_0 V_{REF}}{R_0 R_d} + \frac{V_X V_{REF}}{R_{cx} R_d} + \frac{V_Y V_{REF}}{R_{CY} R_d} + \frac{V_{REF}}{R_c R_d}^2$$

Cross-Product Cancellation

Cross-products are a result of ths V_XV_R and V_YV_R terms. To the extend that $R_1R_b = R_{CX}R_D$, and $R_2R_a = R_{CY}R_d$ cross-product cancellation will occur.

Arithmetic Offset Cancellation

The offset caused by the VREF² term will cancel to the extent that $R_aR_b = R_0R_d$, and the result is:

$$\frac{V_Y V_X}{R_1 R_2} = \frac{V_0 V_{REF}}{R_0 R_d} \text{ or } V_0 = V_X V_Y K$$

where $K = \frac{R_0 R_d}{V_{REF} R_1 R_2}$

Resistor Values

Inputs:

Λ

Δ

١

$$V_X(\min.) \le V_X \le V_X(\max.)$$

$$\Delta V_X = V_X(\max.) - V_X(\min.)$$

$$V_Y(\min.) \le V_Y \le V_Y(\max.)$$

$$\Delta V_Y = V_Y(\max.) = V_Y(\min.)$$

$$V_{REF} = \text{Constant (+7V to +18V)}$$

$$K = \frac{V_0}{V_X V_Y}(\text{Design Requirements})$$

$$R_{1} = \frac{\Delta V_{X}}{200\mu A}, R_{2} = \frac{\Delta V_{Y}}{200\mu A}, R_{d} = \frac{V_{REF}}{250\mu A}$$

$$R_{a} = \frac{\Delta V_{X} V_{REF}}{250\mu A \Delta V_{X} - 200\mu A V_{X}(max.)}$$

$$R_{b} = \frac{\Delta V_{X} V_{REF}}{250\mu A \Delta V_{Y} - 200\mu A V_{Y}(max.)}$$

$$R_{c} = \frac{R_{a}R_{b}}{R_{d}}, R_{CX} = \frac{R_{1}R_{b}}{R_{d}}, R_{cy} = \frac{R_{2}R_{a}}{R_{d}}$$

$$R_0 = \frac{\Delta V_X \Delta V_Y K}{160 \mu A}$$

Multiplying Circuit Offset Adjust

$$\begin{split} 10K &\leq R_5 = R_9 = R_{16} \leq 50K \\ R_7 &= R_{11} = R_{14}, = 100\Omega \\ R_6 &= R_{10} = 100\Omega \ (V_S/0.05) \\ R_{15} &= 100\Omega \ (V_S/0.10) \\ R_8 &= R_1 \mid \mid R_a \\ R_{12} &= R_2 \mid \mid R_b \\ R_{13} &= R_0 \mid \mid R_C \mid \mid R_{CX} \mid \mid R_{CY} \end{split}$$



Figure 5. Multiplying Circuit Offset Adjust

Procedure

- 1. 1.Set all trimmer pots to 0V on the wiper.
- 2. Connect VX input to ground. Put in a full scale square wave on VY input. Adjust XOS(R5) for no square wave on V0 output (adjust for 0 feedthrough).
- 3. Connect V_Y input to ground. Put in a full scale square wave on V_X input. Adjust YOS(R9) for no square wave on V₀ output (adjust for 0 feedthrough).
- 4. 4.Connect VX and VY to ground. Adjust VOS(R16) for 0V on V0 output.

Extended Range Divider



Figure 6. Extended Range Divider

As with the extended range multiplier, resistors R_{az} and R_{ao} are added to cancel the cross-product error caused by the biasing resistors, i.e.

$$\begin{pmatrix} \frac{V_X}{R_1} + \frac{V_0}{R_{ao}} + \frac{V_Z}{R_{az}} + \frac{V_{REF}}{R_a} \end{pmatrix} \begin{pmatrix} \frac{V_{REF}}{R_b} \end{pmatrix} = \begin{pmatrix} \frac{V_0}{R_0} + \frac{V_{REF}}{R_C} \end{pmatrix} \begin{pmatrix} \frac{V_Z}{R_4} + \frac{V_{REF}}{R_D} \end{pmatrix}$$

$$\frac{V_X V_{REF}}{R_1 R_b} + \frac{V_0 V_{REF}}{R_{ao} R_b} + \frac{V_Z V_{REF}}{R_{az} R_b} + \frac{V_{REF}^2}{R_a R_b^2} =$$

$$\frac{V_0 V_Z}{R_0 R_4} + \frac{V_0 V_{REF}}{R_0 R_d} + \frac{V_Z V_{REF}}{R_4 R_c} + \frac{V_{REF}^2}{R_c R_d^2}$$

To cancel cross-product and arithmetic offset:

 $R_{ao}R_b = R_0R_d$, $R_{az}R_b = R_4R_c$ and $R_aR_b = R_cR_d$

and the result is:

$$\frac{V_X V_{REF}}{R_1 R_b} = \frac{V_0 V_Z}{R_0 R_4} \text{ or } V_0 = \frac{V_X}{V_Z K}$$

where $K = \frac{V_{REF} R_0 R_4}{R_1 R_b}$

Notice that it is necessary to match the above resistor crossproducts to within the amount of error tolerable in the output offset, i.e., with a 10V F.S. output, 0.1% resistor crossproduct match will give $0.1\% \times 10V$. untrimmable output offset voltage.

Resistor Values

Inputs:

 $V_X(\min.) \le V_X \le V_X(\max.)$ $\Delta V_X = V_X(\max.) = V_X(\min.)$ $V_Z(\min.) \le V_Z \le V_Z(\max.)$ $\Delta V_Z = V_Z(\max.) = V_Z(\min.)$ $V_{REF} = Constant (+7V to +18V)$

Outputs:

$$V_0 \text{ (min.)} \le V_0 \le V_0 \text{ (max.)}$$
$$\Delta V_0 = V_0 \text{ (max.)} = V_0 \text{ (min.)}$$
$$K = \frac{V_0 V_Z}{V_X} \text{(Design Requirement)}$$

$$R_0 = \frac{\Delta V_0}{750\mu A}, R_b = \frac{\Delta V_{REF}}{250\mu A}, R_4 = \frac{\Delta V_Z}{200\mu A}$$

$$R_{c} = \frac{\Delta V_0 V_{REF}}{750 \mu A \Delta V_0 - 700 \mu A V_0(max.)}$$

$$R_{d} = \frac{\Delta V_{X} V_{REF}}{250 \mu A \Delta V_{Z} - 200 \mu A V_{Z}(max.)}$$

$$R_{a} = \frac{R_{c}R_{d}}{R_{b}}, R_{az} = \frac{R_{c}R_{4}}{R_{b}}, R_{ao} = \frac{R_{0}R_{d}}{R_{b}}$$
$$R_{1} = \frac{\Delta V_{0}\Delta V_{Z}}{600\mu AK}$$

Divider Circuit with Offset Adjustment



Figure 7. Divider Circuit with Offset Adjustment

Divider Circuit Offset Adjustment Procedure

- 1. Set each trimmer pot to 0V on the wiper.
- Connect VX (input) to ground. Put a DC voltage of approximatey 1/2 VZ (max.) DC on the VZ (input) with an AC (squarewave is easiest) voltage of 1/2 VZ (max.) peak-to-peak superimposed on it. Adjust XOS (R5) for zero feedthrough. (No AC at V0)



 Connect VX (input) to VZ (input) and put in the 1/2 VZ(max.) DC with an AC of approximately 20 mV less than VZ(max.).

Adjust ZOS (R13) for zero feedthrough.



65-1868

- Return VX (Input) to ground and connect VZ(max.) DC on VZ(input). Adjust output VOS(R17) for VO = 0VO
- 5. Connect V_X (input) to V_Z (input) and and in V_Z (max.) DC. (The output will equal K.) Decrease the input slowly until the output (V₀ K) deviates beyond the desired accuracy. Adjust Z_{OS} to bring it back into tolerance and return to Step 4. Continue steps 4 and 5 until V_Z reduces to the lowest value desired.

Notice that as the input to VX and VZ gets closer to zero (an illegal state) the system noise will predominate so much that an integrating voltmeter will be very helpful.

Square Root Circuit V₀ = $N\sqrt{V\chi}$





$$\frac{V_X V_{REF}}{R_1 R_b} + \frac{V_{REF}}{R_a R_b}^2 + \frac{V_0 V_{REF}}{R_a o R_b} = \frac{V_0 V_0^2}{R_0 R_4} + \frac{V_0 V_{REF}}{R_c R_4} + \frac{V_0 V_{REF}}{R_0 R_d} + \frac{V_{REF}^2}{R_c R_d}^2$$
If $R_a R_b = R_c R_d$ and $R_{ao} R_b R_0 R_d + R_{ao} R_b R_c R_4 = R_c R_d R_0 R_4$
Then $\frac{V_0^2}{R_0 R_4} = \frac{V_X V_{REF}}{R_1 R_b}$ or $V_0^2 = V_X K$ where $K = \frac{V_{REF} R_0 R_4}{R_1 R_b}$
and $V_0 = N \sqrt{V_X}$ where $N = \sqrt{K}$
 $0 \le V_X \le V_X (max.)$ and $V_0 (max.) = N \sqrt{V_X (max.)}$
 $N = \frac{V_0}{\sqrt{V_X}} (Design Requirements)$
 $R_1 = \frac{V_0 (max.)^2}{74 \mu A N^2}$
 $R_b = R_c = \frac{V_{REF}}{150 \mu A}$
 $R_a = \frac{V_0 (max.)}{50 \mu A}$
 $R_a = \frac{V_0 (max.)}{50 \mu A}$
 $R_b = \frac{V_0 (max.)}{225 \mu A}$

Square Root Circuit Offset Adjust



Figure 9. Square Root Circuit Offset Adjust

 $10K \leq R_5 = R_{13} \leq 50K$

 $R_7 = 100\Omega$

$$R_6 = R_7 \frac{V_S}{0.05}$$

$$\mathbf{R}_8 = \mathbf{R}_1 \| \mathbf{R}_a \| \mathbf{R}_{ao}$$

$$R_9 = R_b$$

$$\mathbf{R}_{10} = \mathbf{R}_0 \| \mathbf{R}_C$$

$$R_{11} = 100 \Omega$$

$$R_{12} = R_{11} \frac{V_S}{0.1}$$

Procedure

- 1. Set both trimmer pots to 0V on the wiper.
- Put in a full scale (0 to V_X(max.) squarewave on V_X input. Adjust X_{OS}(R5) for proper peak-to-peak amplitude on V₀ output. (Scaling adjust)
- 3. Connect V_X input to ground. Adjust V_{OS}(R13) for 0V on V₀ output.

Squaring Circuits $V_0 = K V \chi^2$



Figure 10. Squaring Circuit

$$\frac{{V_X}^2}{{R_1}^2} + \frac{2{V_X}{V_{REF}}}{{R_1}{R_a}} + \frac{{V_{REF}}^2}{{R_a}^2} = \frac{{V_0}{V_{REF}}}{{R_0}{R_d}} + \frac{{V_{REF}}^2}{{R_c}{R_d}} + \frac{{V_X}{V_{REF}}}{{R_c}{R_d}}$$

if
$$R_a^2 = R_c R_d$$
 and $R_1 R_a = 2R_{CX} R_D$

then
$$\frac{V_0 V_{REF}}{R_0 R_d} = \frac{V_X^2}{R_1^2}$$
 or $V_0 = K V_X^2$ where $K = \frac{R_0 R_d}{V_{REF} R_1^2}$

 $V_X(\min.) \le V_X \le V_X(\max.) \quad \Delta V_X = V_X(\max.) - V_X(\min.)$

$$K = \frac{V_0}{V_X^2}$$
 (Design Requirement)

$$R_1 = \frac{\Delta V_X}{200\mu A}$$

$$R_{a} = \frac{\Delta V_{X} V_{REF}}{250 \mu A \Delta V_{X} - 200 \mu A V_{X}(max.)}$$

$$R_{d} = \frac{V_{REF}}{250 \mu A}$$

$$R_{c} = \frac{R_{a}^{2}}{R_{d}}$$

$$R_{cx} = \frac{R_{1}R_{a}}{2R_{d}}$$

$$R_{0} = \frac{\Delta V_{X}^{2}K}{160 \mu A}$$

Squaring Circuits Offset Adjust



Figure 11. Squaring Circuit Offset Adjust



Procedure

- 1. 1.Set both trimmer pots to 0V on the wiper.
- 2. Put in a full scale (±V_X) squarewave on V_X input. Adjust ZOS(R10) for uniform output.
- 3. 3.Connect VX input to ground. Adjust $V_{OS}(R_{11})$ for 0V on V₀ outputs.

There are four types of accuracy errors which affect overall system performance. They are:

- Nonimearity—Incremental deviation from absolute accuracy. See Note 1.
- Scaling Error—Linear deviation from absolute accuracy.
- Output Offset—Constant deviation from absolute accuracy.
- Feedthrough.—Cross-product errors caused by input offsets and external circuit limitations. See Note 2.

This nonlinearity error in the transfer function of the RC4200 is $\pm 0.1\%$ maximum (± 0.03 maximum for the RC4200A). That is,

$$I_3 = \frac{I_1 I_2}{I_4} \pm 0.1\% \text{ F.S.}^{(4)}$$

The other system errors are caused by voltage offsets on the inputs of the RC4200 and can be as high as $\pm 3.0\%$ ($\pm 2.0\%$ for RC4200A).

$$V_0 = \frac{V_X V_Y}{V_Z} \frac{R_0 R_4}{R_1 R_2} \pm 3.0\% \text{ F.S.}^{(3)(4)}$$





Notes:

1. The input circuits tend to become unstable at I1, I2, I4 < 50 μ A and linearity decreases when I1, I2, I4 > 250 μ A (e.g., @ I1 = I2 = 500 μ A nonlinearity error ~ 0.5%).

Figure 12.

- 2. This section will not deal with feedthrough which is proportional to frequency of operation and caused by stray capacitance and/or bandwidth limitations. (refer to Figure 12.)
- 3. Not including resistor tolerance or output offset on the operational amplifier.
- 4. For 50 μ A ≤ I1, I2, I4 ≤ 250 μ A.

Errors Caused by Input Offsets



System errors can be greatly reduced by externally trimming the input offset voltages of the RC4200. ($\pm 3.0\%$ F.S. for RC4200 and $\pm 0.1\%$ for RC4200A.)



If XOS = XOSX, YOS = YOSY, ZOS = -VOSZ,

then
$$V_O \frac{V_X V_Y}{V_Z} \frac{R_0 R_4}{R_1 R_2} \pm 0.3\% \text{ F.S.}^{(3)}$$

Figure 13. RC4200 with Input Offset Adjustment

Extended Range Circuit Errors

The extended range configurations have a disadvantage in that additional accuracy errors may be introduced by resistor product mismatching.

Multiplier

An error in resistor product matching will cause an equivalent feedthrough or output offset error. See Figure 6.

 $R_1R_b = R_CXR_d \pm \alpha$, VX feedthrough (VY = 0) = I α VX

 $R_2R_a = R_{CY}R_d \pm \beta$, V_Y feedthrough ($V_X = 0$) = $\pm \beta V_Y$

 $R_aR_b = R_cR_d \pm \gamma$, V0 offset (VX = VY = 0) = $\pm \gamma V_{REF}^*$

Note:

Output offset errors can always be trimmed out with the output op amp offset adjust, VOS (R16).

Reducing Mismatch Errors

You need not use 0.01% resistors to reduce resistor product mismatch errors. Here are a couple of ways to obtain maximum accuracy out of the extended range multiplier (see Figure 4) using 1% resistors.

Method 1

VX feedthrough, for example, occurs when $V_Y = 0$ and VOSY $\neq 0$. This VX feedthrough will equal $\pm V_X V_{OSY}$. Also, if VOSZ $\neq 0$, there is a VX feedthrough equal to VXVOSZ. A resistor-product error of α will cause a VX feedthrough of $\pm \alpha V_X$. Likewise, VY feedthrough errors are: $\pm V_Y V_{OSX}$, $\pm V_Y V_{OSZ}$ and $\pm \beta V_Y$

Total feedthrough: $\pm V_X V_{OSY} \pm V_Y V_{OSX} \pm \alpha V_X \pm \beta V_Y \pm (V_X + V_Y) V_{OSZ}$

By carefully abusing $XOS(R_5)$, $YOS(R_9)$ and $ZOS(R_{20})$ this equation can be made to very nearly equal zero and the feedthrough error will practically disappear.

A residual of set will probably remain which can be trimmed outwith $VOS(R_{16})$ at the output of amp.

Method 2

Notice that the ratios of R_1R_b :R_{CX}R_d and R_2R_a :R_{CY}R_d are both dependent of R_d also that R₁, R₂, R_a and R_b are all functions of the maximum input requirements. By designing a multiplier for the same input ranges on both V_X and V_Y then R₁ = R₂, R_{CX} = R_{CY} and R_a = R_b. (Note: it is acceptable to design a four quadrant multiplier and use only two quadrants of it.) Select R_d to be 1% or 2% below (or above) the calculated value. This will cause α and β to both be positive (or negative) by nearly the same amount. Now the effective value of R_d can be trimmed with an offset adjustment $Z_{OS}(R_{20})$ on pin 5.

This technique causes: a slight gain error which can be compensated with the R₀ value, and an output of offset error that can be trimmed with $V_{OS}(R_{16})$ on the output op amp.

Extended Range Divider

The only cross-product error of interest is the VZ feedthrough (VX = 0 and VOSX \neq 0) which is easily adjusted with XOS(R5). See Figure 6.

Resistor product mismatch will cause scaling errors (gain) that could be a problem for very low values of V_Z . Adjustments to $YOS(R_{18})$ can be made to improve the high gain accuracy.

Square Root and Squaring

These circuits are functions of single variables so feedthrough, as such, is not a consideration. Cross product errors will effect incremental accuracy that can be corrected $YOS(R_{14})$ or $ZOS(R_{10})$. See Figure 9 and Figure 11.

Appendix 2—Applications

Design Considerations for RMS-to-DC Circuits

Average Value

Consider $V_{in} = Asin\omega\tau$. By definition,

$$V_{AG} = \int_0^{\frac{T}{2}} V_{IN} dt$$

Where T = Period

 $\omega = 2\pi f$ $= \frac{2\pi}{T}$



$$V_{AG} = \frac{2}{T} \int_{0}^{\frac{T}{2}} A \sin \omega t \, dt$$

$$= \frac{2A}{T} \left[-\frac{1}{\omega} \cos \omega t \right]_{0}^{T}$$
$$= \frac{2A}{2\pi} \left[-\cos(\pi) + \cos(0) \right]$$

Average Value of Asin ω t is $\frac{2}{\pi}$ A

RMS Value

Again, consider $V_{IN} = A sin \omega t$

$$\mathbf{V}_{\rm rms} = \sqrt{\mathbf{V}_{\rm AVG}} = \sqrt{\frac{1}{T} \int_0^T [\mathbf{V}_{\rm IN}]^2 dt}$$

 V_{rms} for Asin ω tdt:

$$V_{rms} = \sqrt{\frac{1}{T}} \int_{0}^{T} A^{2} \sin^{2} \omega t \, dt$$

$$V_{rms} = \sqrt{\frac{A^{2}}{T}} \int_{0}^{T} \left[\frac{1}{2} - \frac{1}{2} \cos 2 \cos 2 \omega t\right] dt$$

$$V_{rms} = \sqrt{\frac{A^{2}}{2}} \left[\frac{T}{2} - \frac{1}{4\omega} \sin 2 \omega t\right]_{0}^{T}$$

$$V_{rms} = \sqrt{\frac{A^{2}}{2}} \left[\frac{T}{2}\right]$$

$$V_{rms} = \sqrt{\frac{A^{2}}{2}} \left[\frac{T}{2}\right]$$

Therefore, the rms value of Asinot becomes:

$$V_{rms} = \frac{A}{\sqrt{2}}$$

RMS Value for Rectified Sine Waves

Consider $V_{in} = |A \sin \omega t|$, a rectified wave. To solve, integrate of each half cycle.

i.e.
$$\frac{1}{T} \int_0^T V_{in}^2 dt =$$

$$\frac{1}{T} \left[\int_0^{\frac{T}{2}} A^2 \sin^2 \omega t \, dt + \int_{\frac{T}{2}}^T (-A\sin\omega t)^2 dt \right]$$

This is the same as
$$\frac{1}{1}\int_{0}^{0} TA^{2} \sin^{2} \omega t dt$$

so, $|Asin\omega t|_{rms} = Asin\omega t_{rms}$

Practical Consideration: |Asinwt| has high-order harmonics; Asinwt does not. Therefore, non-ideal integrators may cause different errors for two approaches.



Figure 14.

$$Avg\left[\frac{V_{IN}^{2}}{V_{0}}\right] = V_{0}$$

implies $V_{0} = \sqrt{Avg(|V_{IN}^{2}|)}$
 $V_{0} = \sqrt{Avg |V_{IN}^{2}}$



Figure 15. RMS to DC Converter VOUT= $\sqrt{VIN^2}$

Amplitude Modulator with A.G.C.

In many AC modulator applications, unwanted output modulation is caused by variations in carrier input amplitude. The versatility of the RC4200 multiplier can be utilizes to eliminate this undesired fluctuation. The extended range multiplier circuit (Figure 4) shows an output amplitude inversely proportional to the reference voltage V_{REF}.

i.e.,
$$V_0 = \frac{V_X V_Y}{V_{REF}} \frac{R_0 R_d}{R_1 R_2}$$

By making V_{REF} proportional to V_Y (where V_Y is the carrier input) such that:

$$\mathbf{V}_{\text{REF}} = \mathbf{V}_{\text{H}} = \int (\left| \mathbf{V}_{\text{Y}} \right|)$$

Then the denominator becomes a variable value that automatically provides constant gain, such that the modulating input (VX) modulates the carrier (VY) with a fixed scale factor even though the carrier varies in amplitude. If V_H is made proportional to the average value of Asin ω t (i.e., 2A/ π) and scaled by a value of $\pi/2$ then:

and if: $V_X = Modulating input (V_M)$

and: VY Carrier input (Asinot)

Then:
$$V_0 = K V_M \sin \omega t$$
 where $K = \frac{R_0 R_d}{R_1 R_2}$

The resistor scaling is determined by the dynamic range of the carrier variation and modulating input.

D D

The resistor values are solved, as with the other extended range circuits, in terms of the input voltages.

Input voltages: Modulation voltage (VM): $0 \le VM \le VX(max.)$ Carrier (VY): VY = Asinot Carrier amplitude fluctuation (ΔA): A(min.) sint $\le VY \le A(max.) sin\Omega\omega t$ Dynamic Range (N): A(max.)/A(min.), A(max.) = V_H(max.) and A(min.) = V_H(min.)



Figure 16. Amplitude Modulator with A.G.C.

The maximum and minimum values for I1 and I2 lead to:

$$I_{1}(\max.) = \frac{V_{X}(\max.)}{R_{1}} + \frac{V_{H}(\max.)}{R_{a}} = 250\mu A$$
$$I_{1}(\min.) = \frac{V_{H}(\min.)}{R_{a}} = 50\mu A V_{M}(\min.) = 0$$
$$I_{2}(\max.) = \frac{A(\max.)}{R_{2}} + \frac{V_{H}(\max.)}{R_{a}} = 250\mu A$$
$$I_{2}(\min.) = \frac{V_{H}(\min.)}{R_{a}} = 50\mu A$$

For a dynamic range of N, where

$$N = \frac{A(max.)}{A(min.)} < 5,$$

These equations combine to yield:

$$R_{1} = \frac{V_{X}(\text{max.})}{(5 - N)50\mu\text{A}}, R_{2}\frac{A(\text{max.})}{(5 - N)50\mu\text{A}},$$
$$R_{a} = \frac{A(\text{min.})}{50\mu\text{A}} \text{ and } R_{O} = K \frac{R_{1}R_{2}}{R_{a}},$$

Example 1

 $V_Y = Asinwt 2.5V \le A \le 10V$, therefore N = 4 $0V \le V_M \le 10V$, therefore $V_X(max.) = 10V$ K = 1, therefore $V_0 = V_M sinwt$

$$R_{1} = \frac{V_{X}(\text{max.})}{50\mu\text{A}} = \frac{10\text{V}}{50\mu\text{A}} = 200\text{K}$$

$$R_{1} = \frac{A(\text{max.})}{50\mu\text{A}} = \frac{10\text{V}}{50\mu\text{A}} = 200\text{K}$$

$$R_{a} = \frac{A(\text{min.})}{50\mu\text{A}} = \frac{2.5\text{V}}{50\mu\text{A}} = 50\text{K}$$

$$R_{O} = \text{K}\frac{R_{1}R_{2}}{R_{a}} = 1\frac{200\text{K} \times 200\text{K}}{50\text{K}} = 800\text{K}$$

Example 2

 $V_{Y} = A sin \omega t \ 3 \le A \le 6, \text{ therefore } N = 2$ $0V \le V_{M} \le 8V, \text{ therefore } V_{X}(max.) = 8V$ $K = 0.2, \text{ therefore } V_{0} = 0.2 \text{ V}_{M} \text{ sinwt}$ so: $R_{1} = 53.3K, R_{2} = 40K$ $R_{a} = 60K \text{ and } R_{0} = 7.11K$



Limited Range, First Quadrant Applications

The following circuit has the advantage that cross-product errors are due only to input offsets and nonlinearity error is sightly error is slightly less for lower input currents.

The circuit also has no standby current to add to the noise content, although the signal-to-noise ratio worsens at very low input currents (1-5 μ A) due to the noise current of the input stages.

The RsCs filter circuits are added to each input to improve the stability for input currents below 50 μ A.

Caution!

The bandpass drops off significantly for lower currents ($<50 \ \mu A$) and non-symmetrical rise and fall times can cause second harmonic distortion.

Thermal Symmetry



The scale factor is sensitive to temperature gradients across the chip in the lateral direction. Where possible, the package should be oriented such that forces generating temperature gradients are located physically on the line of thermal symmetry. This will minimize scale-factor error due to thermal gradients.



Figure 18. Outputs



10 100 1K 10K 100K Frequency (Hz)

1M

Figure 20. AC Feedthrough vs. Frequency

1.0

Mechanical Dimensions

8-Lead SOIC Package

Symbol	Inches		Millimeters		Millimeters		Notes	
Symbol	Min.	Max.	Min.	Max.	Notes			
А	.053	.069	1.35	1.75				
A1	.004	.010	0.10	0.25				
В	.013	.020	0.33	0.51				
С	.008	.010	0.20	0.25	5			
D	.189	.197	4.80	5.00	2			
Е	.150	.158	3.81	4.01	2			
е	.050	.050 BSC		BSC				
Н	.228	.244	5.79	6.20				
h	.010	.020	0.25	0.50				
L	.016	.050	0.40	1.27	3			
N	8	3	8		6			
α	0°	8°	0°	8°				
CCC	_	.004	_	0.10				

Notes:

- 1. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- 2. "D" and "E" do not include mold flash. Mold flash or protrusions shall not exceed .010 inch (0.25mm).
- 3. "L" is the length of terminal for soldering to a substrate.
- 4. Terminal numbers are shown for reference only.
- 5. "C" dimension does not include solder finish thickness.
- 6. Symbol "N" is the maximum number of terminals.







PRODUCT SPECIFICATION

Mechanical Dimensions (continued)

8-Lead Plastic DIP Package

Symbol	Inc	hes	Millin	Notos	
Symbol	Min.	Max.	Min.	Max.	Notes
А	_	.210	_	5.33	
A1	.015	—	.38		
A2	.115	.195	2.93	4.95	
В	.014	.022	.36	.56	
B1	.045	.070	1.14	1.78	
С	.008	.015	.20	.38	4
D	.348	.430	8.84	10.92	2
D1	.005	_	.13	_	
E	.300	.325	7.62	8.26	
E1	.240	.280	6.10	7.11	2
е	.100	BSC	2.54 BSC		
eВ	_	.430	_	10.92	
L	.115	.160	2.92	4.06	
Ν	8	°°	8	3°	5





- 1. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- 2. "D" and "E1" do not include mold flashing. Mold flash or protrusions shall not exceed .010 inch (0.25mm).
- 3. Terminal numbers are for reference only.
- 4. "C" dimension does not include solder finish thickness.
- 5. Symbol "N" is the maximum number of terminals.

Mechanical Dimensions (continued)

8-Lead Ceramic DIP Package

Symbol	Inches		es Millimeters		
Symbol	Min.	Max.	Min.	Max.	Notes
Α	_	.200	_	5.08	
b1	.014	.023	.36	.58	8
b2	.045	.065	1.14	1.65	2, 8
c1	.008	.015	.20	.38	8
D	_	.405	_	10.29	4
Е	.220	.310	5.59	7.87	4
е	.100	BSC	2.54	BSC	5, 9
eA	.300	BSC	7.62	BSC	7
L	.125	.200	3.18	5.08	
Q	.015	.060	.38	1.52	3
s1	.005		.13		6
α	90°	105°	90°	105°	

Notes:

- 1. Index area: a notch or a pin one identification mark shall be located adjacent to pin one. The manufacturer's identification shall not be used as pin one identification mark.
- 2. The minimum limit for dimension "b2" may be .023 (.58mm) for leads number 1, 4, 5 and 8 only.
- 3. Dimension "Q" shall be measured from the seating plane to the base plane.
- 4. This dimension allows for off-center lid, meniscus and glass overrun.
- The basic pin spacing is .100 (2.54mm) between centerlines. Each pin centerline shall be located within ±.010 (.25mm) of its exact longitudinal position relative to pins 1 and 8.
- 6. Applies to all four corners (leads number 1, 4, 5, and 8).
- 7. "eA" shall be measured at the center of the lead bends or at the centerline of the leads when " α " is 90°.
- 8. All leads Increase maximum limit by .003 (.08mm) measured at the center of the flat, when lead finish applied.
- 9. Six spaces.







Ordering Information

Part Number	Package	Operating Temperature Range
RC4200N	8-Lead Plastic DIP	0°C to +70°C
RC4200AN	8-Lead Plastic DIP	0°C to +70°C
RC4200M	8-Lead SOIC	0°C to +70°C
RC4200AM	8-Lead SOIC	0°C to +70°C
RM4200D	8-Lead Ceramic DIP	-55°C to +125°C
RM4200AD	8-Lead Ceramic DIP	-55°C to +125°C
RM4200AD/883B	8-Lead Ceramic DIP	-55°C to +125°C

Note:

/883B suffix denotes MIL-STD-883, Level B processing

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com